Total No. of Questions: 6

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Enrollment No.....



Q.1

Faculty of Engineering / Science End Sem Examination Dec-2023 CS3CO33 / EC3CO07 / IT3CO26 / BC3CO38

Digital Electronics

Programme: B.Tech. / B.Sc. Branch/Specialisation: CSE All / EC / IT / Computer Science

Duration: 3 Hrs.

Maximum Marks: 60

Note: All questions are compulsory. Internal choices, if any, are indicated. Answers of Q.1 (MCQs) should be written in full instead of only a, b, c or d. Assume suitable data if necessary. Notations and symbols have their usual meaning.

i.	A+A=A defined by-			
	(a) Null law (b) Idempotent law	(c) Identity law (d) None of these		
ii.	canonical form is a unique way of representing-			
	(a) SOP	(b) POS(d) Boolean Expressions		
	(c) Minterm			
iii.	In two input XNOR, one input is A & another is always ground then			
	output is:			
	(a) 0 (b) 1	(c) A (d) A'		
iv.	Which gate is used as comparator?		1	
	(a) NAND (b) NOR	(c) XNOR (d) XOR		
v.	The basic latch consists of	·	1	
	(a) Two inverters	(b) Two comparators		
	(c) Two amplifiers	(d) Two adders		
vi.	What is an ambiguous condition in a NAND based S'-R' latch?			
	(a) $S'=0$, $R'=1$	(b) $S'=1$, $R'=0$		
	(c) $S'=1$, $R'=1$	(d) $S'=0$, $R'=0$		
vii.	ROM internal structure consist of-		1	
	(a) NAND and XOR arrays	(b) NOR and NAND arrays		
	(c) Decoder and OR	(d) OR and AND arrays		
viii.	The full form of PLA is		1	
		(b) Programmable Logic Array		
	(c) Program Logic array	(d) Printed Logical array		
ix.				
	(a) EEPROM (b) EPROM	(c) PROM (d) Mask Rom		

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	х.	Which ROM can be erased by an electrical signal?					
		(a) ROM (b) Mask ROM	(c) EPROM	(d) EEPROM			
Q.2	i.	Determine the value of base x if $(211)_x = (152)_8$.					
	ii.	ct of maxterm.	3				
	iii.	. Express the following function as the minimal sum of products using					
		K-map.					
		$F(a,b,c,d)=\sum (0,2,4,5,6,11,13,$	$15)+\sum d(8,10,1)$	4)			
OR	iv.	Reduce the following using tabulation method.					
Q.3	i.	Implement the Boolean functions using basic logic gates-					
		(a) $ABC'+(A'+B')C$ (b) AB	C				
	ii.	Define encoder & decoder.			3		
	iii.	uth table & Boolean	an 5				
		equation.					
OR	iv.	Implement the Boolean function usin	g 8:1 mux.		5		
		F(A, B, C, D) = A'BD'	+ACD+B'CD-	+A'C'D.			
Q.4	i.	Convert SR FF to JK FF using suitab	le diagram.		3		
	ii.	Define shift registers. Describe any two shift register with example.					
OR	iii.	Design a circuit for 3-bit synchronou	s up counter u	sing T flip-flop.	7		
Q.5	i.	Write types of memories. Which mer	nory is called	volatile? Why?	4		
	ii.	Compare the PROM, EPROM and E	EPROM.	-	6		
OR	iii.	Explain dynamic RAM.			6		
Q.6		Attempt any two:					
	i.	Explain the two inputs TTL NAND gate using neat circuit diagram.					
	ii.	Write a short note on DTL & RTL.					
	iii.	Write a short note on CMOS family.			5		
